Hits	Search Text	DB	Time stamp
27375	semiconductor and (tft or (thin adj film	USPAT;	2004/03/02
	adj transistor))	US-PGPUB;	09:51
		EPO; JPO;	
		DERWENT;	
		IBM TDB	
343	(semiconductor and (tft or (thin adj film	USPAT;	2004/03/02
		US-PGPUB;	09:53
		EPO; JPO;	
		DERWENT;	
		IBM TDB	
343	((semiconductor and (tft or (thin adi	USPAT;	2004/03/02
		1	10:41
		EPO; JPO;	
	and substrate		1
237	(semiconductor and (tft or (thin add film	USPAT;	2004/03/02
	, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	10:42
	, ,		
	((and	1	
		I	
	27375 343 343	27375 semiconductor and (tft or (thin adj film adj transistor)) 343 (semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or ((aluminum adj nitride) and oxygen)) 343 ((semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or ((aluminum adj nitride) and oxygen))) and substrate	27375 semiconductor and (tft or (thin adj film adj transistor)) 343 (semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or (aluminum adj nitride) and oxygen)) 343 ((semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or DERWENT; IBM_TDB USPAT; ((semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or (aluminum adj nitride) and oxygen))) and substrate 237 (semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or USPAT; adj transistor))) and (alno or alon or USPAT; adj transistor))) and (alno or alon or USPAT; USPAT; adj transistor))) and (alno or alon or USPAT;